

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	{10524379	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/30 17:44
S3	86	{parametric near2 (value or variable or variation)) same (integrated near2 circuit)	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/30 18:40
S4	61	{S3 and (@ad or @riad) < "20030601"	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/30 18:41
S5	13	{S4 and identification	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/30 18:42
S6	4001	{16/4,8.ccls.	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/30 18:44
S7	3000	{S6 and (@ad or @riad) < "20030601"	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/30 18:44
S8	3	{(cell or ic or chip) with identification) and ((resistance or resistor or resistive) with parametric near3 (value variation variable))	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 14:58
S9	2	{2003/0151539	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:02
S10	2	{20030151539"	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:03
S11	3	{2003/0151942	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:07
S12	2	{20030151942"	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:07
S13	13	{identification and (resistor with (silicide and insular\$3))	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:21
S14	4	{(resistor with (silicide and insular\$3)) same (resistance with variation)	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:41
S15	1005	{(cell or ic or chip) with identification) and ((resistance or resistor or resistive) with (parameter or parametric or variation))	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:50
S16	908	{(resistance or resistor or resistive) same silicide same shape)	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:52
S17	1	{S15 and S16	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:52
S18	18	{S15 and silicide	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 15:52
S19	98	{(identify\$3 or identification) near4 ((integrated near circuit) or chip)) and ((resistor or resistance or resistive) near4 (parameter or parametric))	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 16:00
S20	88	{S19 and (@ad or @riad) < "20030601"	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 16:00
S21	10	{20030086284"   "4646266"   "5745407"   "5835396"   "6034882"   "6185121"   "6185122"   "6208545"   "6236587"   "6549447".PN. OR ("6649505").URPN.	US.PGPUB; USPAT; USOCR	OR	ON	2007/08/31 16:08
S22	1	{10/364759	US.PGPUB; USPAT; USOCR	OR	ON	2007/08/31 18:04
S23	16	{20030056122"   "20030151539"   "20050162892"   "20050173779"   "3636530"   "5708291"   "5818738"   "5969404"   "6115283"   "6161213"   "6258700"   "6297083"   "6337507"   "6400632"   "6469923"   "6836430".PN.	US.PGPUB; USPAT; USOCR	OR	ON	2007/08/31 18:06
S24	4	{S20 and (silicide)	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 18:11
S25	8	{20010050952"   "3636530"   "3911368"   "4023110"   "5608645"   "5686650"   "6122191"   "6363011".PN. OR ("6836430").URPN.	US.PGPUB; USPAT; USOCR	OR	ON	2007/08/31 18:23
S26	709	{(resistor with (silicide or salicide) and (integrated near circuit)	US.PGPUB; USPAT; USOCR	OR	ON	2007/08/31 18:26
S27	3	{S26 and (resistor with parametric)	US.PGPUB; USPAT; USOCR	OR	ON	2007/08/31 18:27
S28	2	{(identify\$3 or identification) near4 ((integrated near circuit) or chip)) same ((resistor or resistance or resistive) near4 (parameter or parametric))	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 18:42
S29	383	{(identify\$3 or identification) near4 ((integrated near circuit) or chip)) same (resistor or resistance or resistive)	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 18:43
S30	276	{identification near4 ((integrated near circuit) or chip)) same (resistor or resistance or resistive)	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 18:45
S31	39	{S30 and (silicide or salicide)	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 18:51
S32	1869	{integrated and circuit and (identify\$3 or identification)).ti.	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 18:58
S33	11	{integrated and circuit and (self near (identify\$3 or identification))).ti.	US.PGPUB; USPAT; USOCR; EPO; IPO; DERWENT; IBM_TDB	OR	ON	2007/08/31 19:01
S34	15	{S26 and (shape with (silicide or salicide))	US.PGPUB; USPAT; USOCR	OR	ON	2007/08/31 19:27